

# DIGITRON SEMICONDUCTORS

1N3889-1N3893

FAST RECOVERY RECTIFIER

## MAXIMUM RATINGS

Parameter	Symbol	1N3889	1N3890	1N3891	1N3892	1N3893
Working peak reverse voltage	$V_{RWM}$	50V	100V	200V	300V	400V
Peak repetitive reverse voltage	$V_{RRM}$	50V	100V	200V	300V	400V
Operating temperature range	$T_J$		-65 to +150°C			
Storage temperature range	$T_{STG}$		-65 to +175°C			
Maximum thermal resistance	$R_{SJC}$		2.0°C/W junction to case			
Mounting torque			12-15 inch pounds			
Weight			.16 ounces (5.0 grams) typical			

Add "R" to part numbers for reverse polarity.

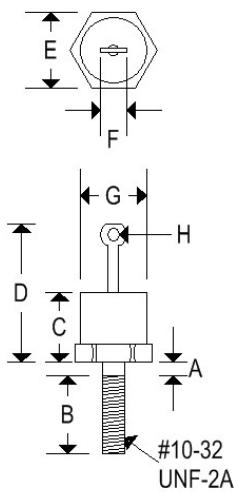
## ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Value	Test Condition
Average forward current	$I_{F(AV)}$	12 Amps	$T_C = 100^\circ C$ , square wave, $R_{SJC} = 2.0^\circ C/W$
Maximum surge current	$I_{FSM}$	175 Amps	8.3ms, half-sine, $T_C = 100^\circ C$
Maximum peak forward voltage	$V_{FM}$	1.50 Volts	$I_{FM} = 38A$ : $T_J = 25^\circ C^*$
Maximum peak reverse current	$I_{RM}$	10 $\mu A$	$V_{RRM}$ , $T_J = 25^\circ C$
Maximum peak reverse current	$I_{RM}$	2.0 mA	$V_{RRM}$ , $T_J = 150^\circ C$
Maximum reverse recovery time	$t_{RR}$	200ns	$I_F = 1A$ dc, $V_R = 30V$ , $dI/dt = 25A/\mu s$ , $T_C = 55^\circ C$
Typical junction capacitance	$C_J$	115pF	$V_R = 10V$ , $f = 1MHz$ , $T_J = 25^\circ C$

- Pulse test: pulse width 300 $\mu$ sec. Duty cycle 2%

## MECHANICAL CHARACTERISTICS

Case	DO-4(R)
Marking	Alpha-numeric
Normal polarity	Cathode is stud
Reverse polarity	Anode is stud (add "R" suffix)



	DO-4(R)			
	Inches		Millimeters	
	Min	Max	Min	Max
A	-	0.078	-	1.981
B	0.422	0.453	10.719	11.506
C	-	0.405	-	10.287
D	-	0.800	-	20.320
E	0.420	0.440	10.668	11.176
F	-	0.250	-	6.350
G	-	0.424	-	10.770
H	0.066	-	1.676	-

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).

Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

# DIGITRON SEMICONDUCTORS

**1N3879-1N3883**

**FAST RECOVERY RECTIFIER**

Figure 1  
Typical Forward Characteristics

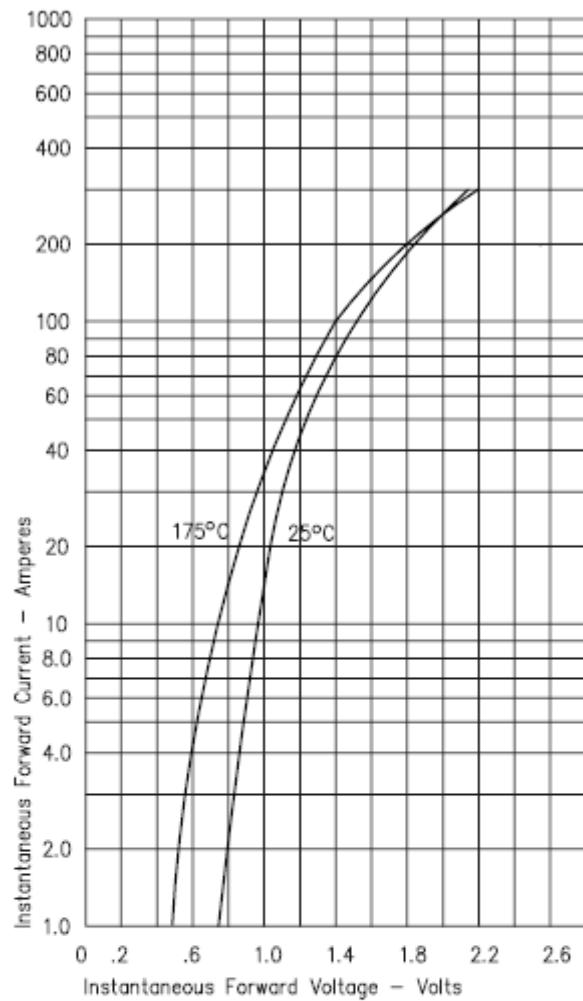


Figure 2  
Typical Reverse Characteristics

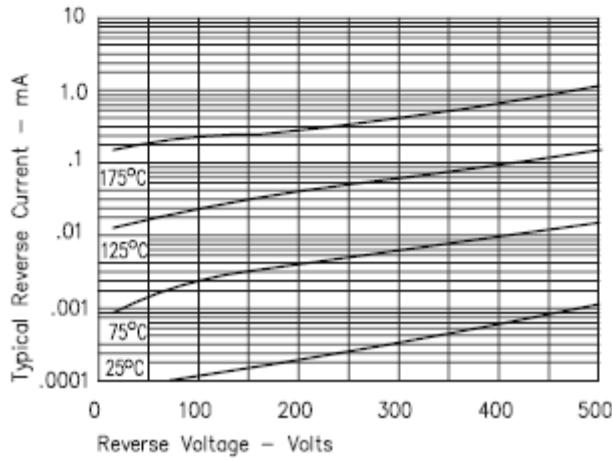


Figure 3  
Typical Junction Capacitance

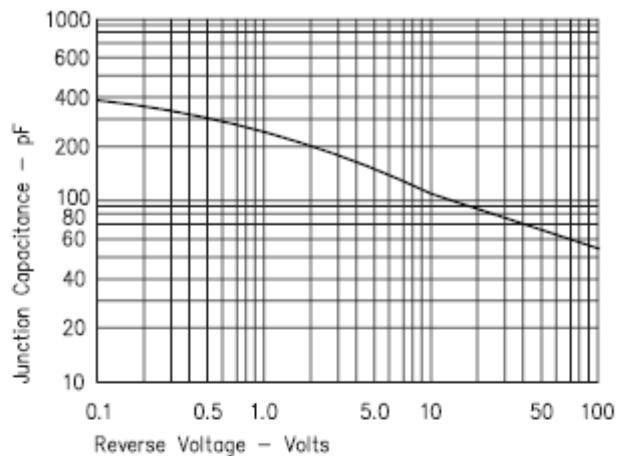


Figure 4  
Forward Current Derating

